



# **High-Power Diffraction-Limited Laser Systems with Variable Output Characteristics Oscillating in Visible Spectral Range on Atomic Copper Self-terminating Transitions for Advanced Material Microprocessing**

**I. K. Kostadinov, K. A. Temelkov, S. I. Slaveeva and G. P. Yankov**

**Institute of Solid State Physics, Bulgarian Academy of Sciences  
72 Tzarigradsko Chaussee, 1784 Sofia, BULGARIA**

**[temelkov@issp.bas.bg](mailto:temelkov@issp.bas.bg)**

## Introduction

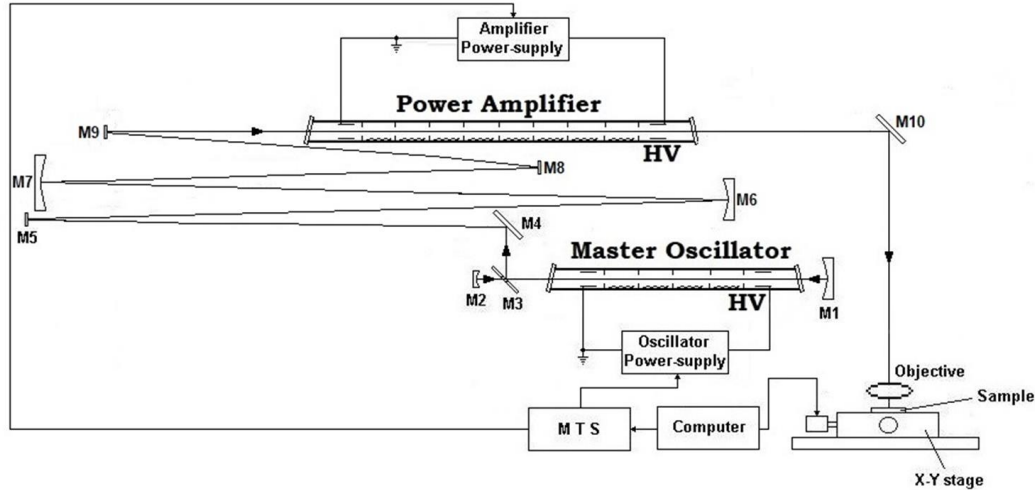
Though the continuous development of **copper vapour lasers** and their low-temperature variants (**copper halide vapor** and **HyBrID copper lasers**), which are **the most powerful lasers in the visible spectral region**, toward the design of **compact reliable sealed-off lasers** is quite successful, the competing with the **solid state lasers** operating in the **visible spectral range** via **second harmonic generation** is far from over. **Commercial solid state lasers** produced by leading laser companies usually delivers TEM<sub>00</sub> Gaussian laser beam, i. e. beam propagation factor  $M^2$  is well in the range between **1.05** and **1.3**, while metal vapor lasers produce **partially or near diffraction-limited laser radiation** (up to **90 %** of the laser output is diffraction-limited) with a record-low  $M^2 = 1.3$ , due to the short laser pulse and a small number of the cavity round-passes. The Master Oscillator – Power Amplifier (**MO–PA**) system based on the atomic Cu bromide (**CuBr**) vapor laser is well established as a laser source used for precise micromachining in the industry for drilling, cutting, scribing, marking, welding, etc. of various materials. Though the development and operation difficulties, the atomic **Cu vapor laser** has **unsurpassable advantages** over the **Cu halide vapor lasers**, namely **lasing stability**, **higher laser pulse energy** at the same average output power, **two-time shorter laser pulse**, the possibility to operate with **small-bore laser tubes** (the aperture smaller than **4 mm**), etc.

## Aims

To develop and investigated a new considerably improved MO–PA laser systems delivering high-power diffraction-limited laser radiation ( $M^2 = 1$ ) at the atomic copper 510.6- and 578.2-nm lines, as follows:

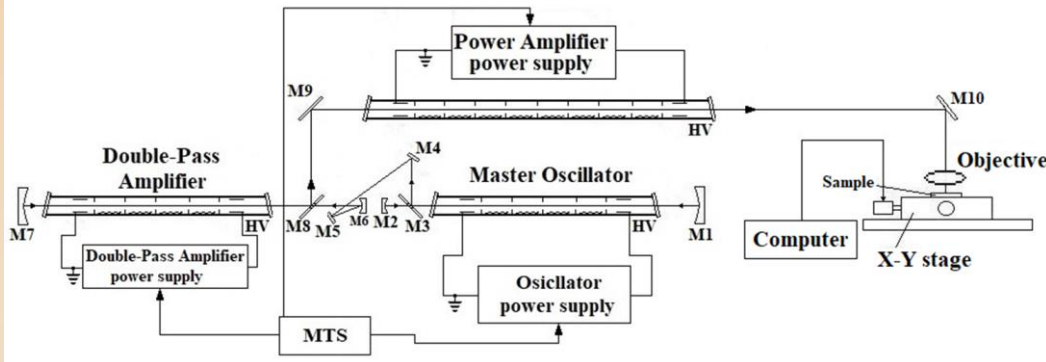
- 1) as a Master Oscillator (MO), to compare laser characteristics of CuBr vapor MO operating with a negative branch unstable resonator (NBUR) and small-bore Cu vapor MO oscillating with a flat-flat stable cavity and a NBUR;
- 2) to compare two CuBr vapor laser tubes with a significantly enhanced active volume as a Power Amplifier (PA), in order to increase considerably the output parameters;
- 3) to realize various designs of the MO–PA laser systems, namely single- and double-pass PAs (PA and DPA), matching telescopes (MTs) with different magnifications  $M$ ;
- 4) laser radiation is applied in precise micron-sized material processing of silicon (Si) using achromatic short-focus focusing lenses.

# Experimental setup



(a)

**Fig. 1. Schematic diagram of studied MO-PA (a) and MO-DPA-PA (b) laser systems.**



(b)

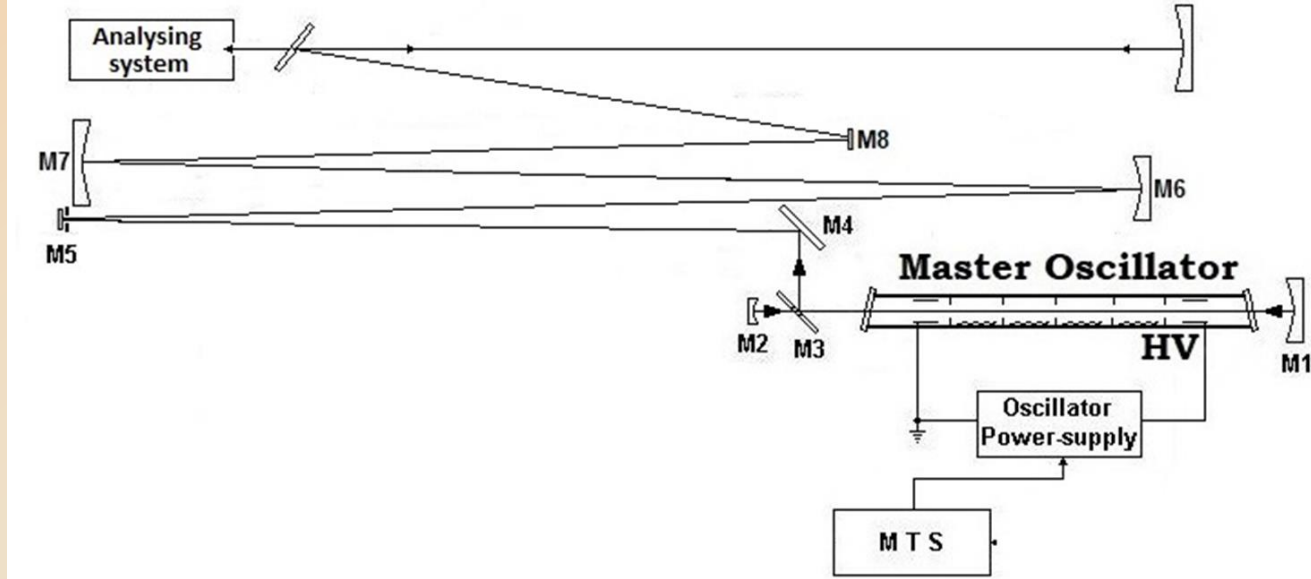
**Table 1. Parameters of optical elements, namely mirrors, lenses, diaphragms.**

Optics	M1	M2	M3	M4	M5	M6	M7	M8	M9	M10	Objective	
Focal length (cm)	75	5	$\infty$	Orifice diameter 0.6 mm	$\infty$	$\infty$	120	250	$\infty$	$\infty$	$\infty$	2, 3, 4, 6, 12 20, 40, 100
Focal length (cm)	100	5	$\infty$	Orifice diameter 1 mm	$\infty$	$\infty$	12.5	250	$\infty$	$\infty$	$\infty$	2, 3, 4, 6, 12 20, 40, 100

# Experimental results

## First method for $M^2$ experimental determination

$$M^2 = \frac{\theta}{\theta_{00}} = \frac{\pi}{4\lambda f} Dd$$



**Fig. 2. Experimental setup for  $M^2$  determination.**

**Table 2.** Laser beam divergence for 510.6-nm wavelength:  $D$  – laser beam diameter;  $d^{exp}$  – laser spot diameter measured in focal plane of concave mirror with focal distance of 2.5 m;  $\theta^{exp}$  – experimentally determined laser beam divergence using the expression  $\theta^{exp} = d^{exp} / f$ ;  $\theta_{00}$  – laser beam divergence calculated for TEM<sub>00</sub> Gaussian beam with diameter  $D$ ;  $M^2 = \theta^{exp} / \theta_{00}$ .

$D$ (mm)	$d^{exp}$ ( $\mu\text{m}$ )	$\theta^{exp}$ ( $\mu\text{rad}$ )	$\theta_{00}$ ( $\mu\text{rad}$ )	$M^2$
5	$330 \pm 20$	$132 \pm 8$	130.0	<b>1.02</b>
10	$165 \pm 10$	$66 \pm 4$	65.0	<b>1.02</b>
15	$110 \pm 10$	$44 \pm 4$	43.3	<b>1.02</b>
20	$82 \pm 5$	$33 \pm 2$	32.5	<b>1.02</b>
25	$67 \pm 5$	$27 \pm 2$	26.0	<b>1.04</b>

## Experimental results

### Second method for $M^2$ experimental determination

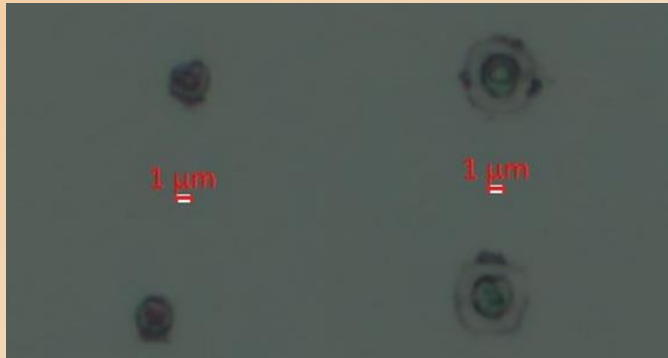
$$I_{th} = \frac{4P_{out}^p}{\pi \cdot d^2} = \frac{4E}{\pi \cdot d^2 \tau_p} = \frac{4P_{out}^{av}}{\pi \cdot d^2 prf \cdot \tau_p} \Rightarrow d = \sqrt{\frac{4P_{out}^{av}}{\pi \cdot prf \cdot \tau_p \cdot I_{th}}}$$

Table 3. Laser spot diameter determined through volumetric optical breakdown for 510.6-nm wavelength:  $f$  – focal distance;  $P_{out}^{av}$  – threshold average output power;  $I_{th1}$  and  $I_{th2}$  – threshold laser intensity taken from the references;  $d_{exp1}$  and  $d_{exp2}$  – laser spot diameter experimentally determined using  $I_{th1}$  and  $I_{th2}$ , respectively;  $d_{th} = f \cdot \theta_{00}$ ;  $prf$  – 20 kHz,  $\tau_p = 20$  ns.

$D$ (mm)	$f$ (cm)	$P_{out}^{av}$ (W)	$I_{th1}$ (GW.cm <sup>-2</sup> )	$I_{th2}$ (GW.cm <sup>-2</sup> )	$d_{exp1}$ ( $\mu$ m)	$d_{exp2}$ ( $\mu$ m)	$d_{th}^h$ ( $\mu$ m)	$M^2_1$	$M^2_2$	$M^2_{1av}$	$M^2_{2av}$	$M^2_{av}$
20	2	0.200	44.7	100	1.2	0.8	0.65	1.85	1.23	1.328	0.874	1.101
	6	0.750			2.3	1.5	1.95	1.18	0.78			
	12	1.500			3.3	2.2	3.90	0.85	0.56			
30	4	0.400	44.7	100	1.7	1.1	0.87	1.95	1.26	1.328	0.874	1.101
	12	0.600			2.1	1.4	2.60	0.81	0.54			

## Experimental results

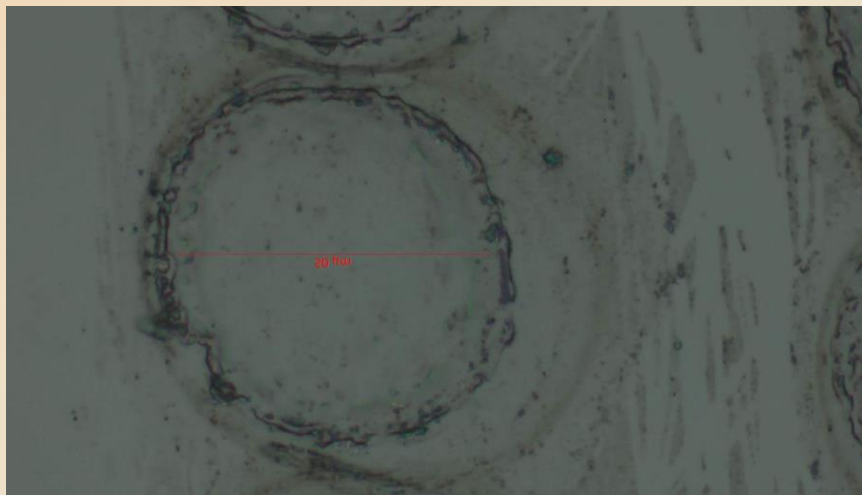
Precise microprocessing of Si samples at various focusing distances and average output powers



(a)



(b)



(c)

**Fig. 3. Microcraters and microchannels drilled or cut at 2- (a) and (b) and 100-cm focusing distances (c) with 10- (left image) and 100-mW (right image) average laser power in Si samples.**

## Conclusions

The highest beam quality achieved so far with laser systems oscillating on the metal self-terminating transitions is confirmed by precise measurement of the threshold average output power for volumetric optical breakdown at different focusing distances  $f$  and a known breakdown threshold  $I_{th}$ . Laser radiation with both record-high average output power of 50 W and beam quality is obtained. Precised micromachining of Si samples with crater diameter or trench width of 1.5  $\mu\text{m}$  is accomplished applying achromatic 2-cm focusing lens.

## Acknowledgements

This work was supported by the Project KP-06-H37/2 “Basic research and development of high-beam-quality high-power laser system oscillating in visible spectral range” of Bulgarian National Science Fund.